## NSN 5961-01-368-9745

Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-368-9745 **Inclosure Material:** Plastic **Overall Length:** 4.25 millimeters **Terminal Length:** 25.0 millimeters **Overall Diameter:** 1.85 millimeters Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-35 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 5.6 forward voltage, dc **Current Rating Per Characteristic:** 10.00 milliamperes all primaries pascal **Power Rating Per Characteristic:** 400.0 milliwatts any acceptable preset **Capacitance Rating In Picofarads:** 140.0 **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No